



YEA SHIN TECHNOLOGY CO., LTD

YSESD0502TL

Ultra Low Capacitance TVS/ESD Protection Diode



DESCRIPTION

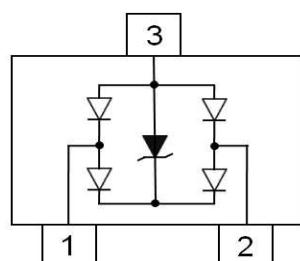
GESD0502TL is an ultra-low capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of 0.2pF (I/O to I/O) only, GESD0502TL is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 ($\pm 15\text{kV}$ air, $\pm 8\text{kV}$ contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

GESD0502TL uses small SOT-23 package. Each GESD0502TL device can protect two high-speed data lines. The combined features of low capacitance, small size and high ESD robustness make GESD0502TL ideal for high-speed data port and high-frequency line applications. The low clamping voltage of the GESD0502TL guarantees a minimum stress on the protected IC.

ORDERING INFORMATION

- ◊ Device: GESD0502TL
- ◊ Package: SOT-23
- ◊ Marking: 52L
- ◊ Material: Halogen free
- ◊ Packing: Tape & Reel
- ◊ Quantity per reel: 3,000pcs

PIN CONFIGURATION



FEATURES

- ◊ Transient protection for high-speed data lines
IEC 61000-4-2 (ESD) $\pm 15\text{kV}$ (Air)
 $\pm 8\text{kV}$ (Contact)
- IEC 61000-4-4 (EFT) 40A (5/50 ns)
Cable Discharge Event (CDE)
- ◊ Small package (2.9mm×2.4mm×1.0mm)
- ◊ Protects two data lines
- ◊ Low capacitance: 0.2pF Typical (I/O-I/O)
- ◊ Low leakage current
- ◊ Low clamping voltage

MACHANICAL DATA

- ◊ SOT-23 package
- ◊ Flammability Rating: UL 94V-0
- ◊ Packaging: Tape and Reel
- ◊ High temperature soldering guaranteed: 260/10s
- ◊ Reel size: 7 inch

APPLICATIONS

- ◊ Serial ATA
- ◊ Desktops, Servers and Notebooks
- ◊ PCI Express
- ◊ MDDI Ports
- ◊ USB Data Line Protection
- ◊ Display Ports
- ◊ Digital Visual Interfaces (DVI)

PACKAGE OUTLINE



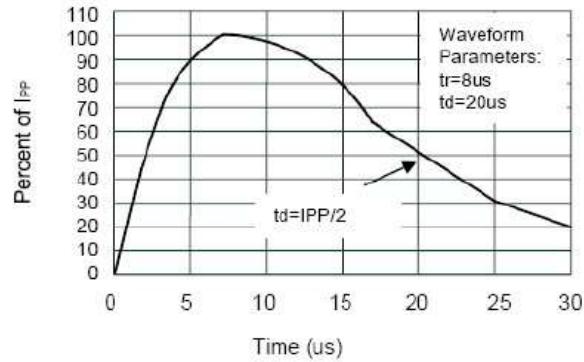
YSESD0502TL

ABSOLUTE MAXIMUM RATING			
Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (8/20μs)	60	W
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV
T _{OPT}	Operating Temperature	-55/+125	°C
T _{STG}	Storage Temperature	-55/+150	°C

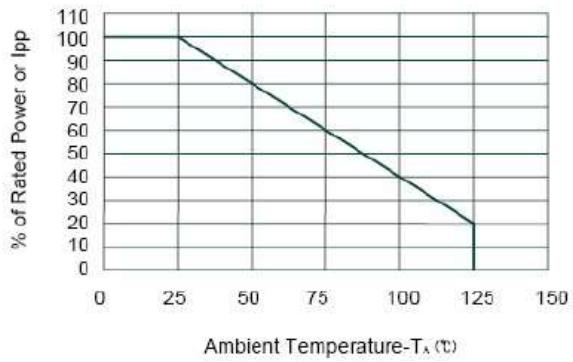
ELECTRICAL CHARACTERISTICS (Tamb=25°C)						
Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V _{RWM}	Reverse Working Voltage	I/O to GND			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA Between I/O and GND	6.0			V
I _R	Reverse Leakage Current	V _{RWM} = 5V Between I/O and GND			100	nA
V _C	Clamping Voltage	I _{PP} = 1A, t _p = 8/20μs Between I/O and GND			10	V
		I _{PP} = 4A, t _p = 8/20μs Between I/O and GND			15	V
V _F	Forward Voltage	I _T = 10mA Between I/O and GND			1.2	V
C _T	Total Capacitance	V _R = 0V, f = 1MHz Between I/O and GND		0.4		pF
		V _R = 0V, f = 1MHz Between I/O and I/O		0.2		pF

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ELECTRICAL CHARACTERISTICS CURVE

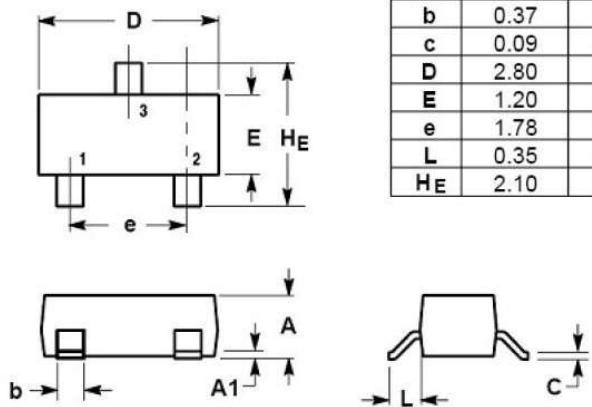


Pulse Waveform



Power Derating Curve

SOT-23 PACKAGE OUTLINE DIMENSIONS



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A ₁	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.35	0.54	0.69	0.014	0.021	0.029
H _E	2.10	2.40	2.64	0.083	0.094	0.104